phs memory®

4GB Computer memory DDR3 for Samsung NP-R730-JT0BFR SO DIMM



PHS-memory® - computer memory with 100% quality

- many years of IT competence
- Free support for optimal configuration and product selection
- High availability through professional warehouse management
- Fast delivery in throughout Europe
- Short response times and professional order processing due to full digitalization throughout the entire process with complete traceability
- Incoming goods inspection include checks of the DRAMs, PCBs and the programmed SPDs in order to exclude possible errors (Controlled BOM).
- PHS-memory® brand memories guarantee 100% compatibility to the specified system.
- PHS-memory® memories can be used together with existing memories in the device depends on to the configuration rules of the system.
- The "fallback option" in the SPD of PHS-memory® allows DRAMs with higher clock rates to be operated together with older memory modules with lower clock rates within the system.
- Products with unique serial number for service and warranty
- Pre-sales and after-sales support by technically trained personnel



Memory Specification



Memory size	4GB			
Memory technology	DDR3			
ECC support	NO			
JEDEC Norm	PC3-8500S			
DRAM Organization	256Mx8			
Rank	2Rx8			
Туре	SO DIMM			
Number of pins	204 Pin DIMM			
Memory data transfer rate	1066MHz @ CL7			
Voltage	1,5 Volt			
Speciality	-			
Board dimensions	67,6 x 30 (LxB mm)			
Operating temperature	0° C - 85° C			
Storage temperature	-40° C - +95° C			
RoHS compliant	yes			
SKU	SP544957			
EAN	4069169128785			

Note: The module specified in this datasheet is one of several possible configurations available under this part number.

Some details may differ from the specifications described here and the illustration, but have no negative influence on the functionality.



System Specifications

The memory is 100% compatible with this sytem:

System manufacturer	Samsung
Device type	Laptop
Device family	Notebook NP-R
Device series	NP-R730 Serie
Device name	NP-R730-JT0BFR
Standard memory	4GB (2x2GB)
Maximum memory*	8GB
Number of memory sockets	2

* The specifications for the maximum memory upgrade may differ from those of the manufacturer Samsung. Often the information given in the manual for the maximum memory upgrade is not up to date. New memory technologies, bios updates or newer software versions often allow the use of memory modules with a higher capacity than specified by the manufacturer with the same performance and stability.

Information on memory installation

- Turn off the system
- Remove the plug of the power supply unit (if connected)
- Remove the battery, according to the user manual of the system
- Always ground yourself before touching electronic components
- Protect the memory module from static voltages:
- Do not touch the gold pins of the memory module
- Only touch the sides of the memory module
- Use a grounding strap and/or ESD glove if possible

General installation instructions are supplied by E-Mail.



Further memory options for Samsung NP-R730-JT0BFR

Size	SKU	Technology	Туре	Number of pins	Brand	Reference no.
4GB	SP544957	DDR3	SO DIMM	204 Pin DIMM	PHS-memory®	

PHS-memory® warranty

Every PHS-memory® is equipped with a 5-years-warranty of perfect operation. If the RAM module is defective or fails within 5 years of purchase when used properly, you will receive an appropriate RAM module free of charge. If a suitable memory module is no longer available, we will refund the purchase price.





Contact Information

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All information without guarantee. Technical changes and errors excepted. You can find current price information in our online shop at https://www.phs-memory.it